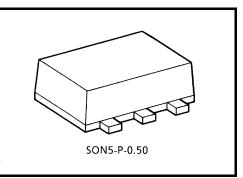
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SGU04FE

Inverter (Un-Buffer)

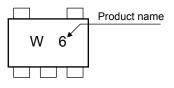
Features

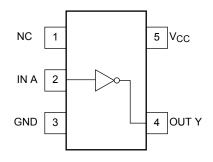
- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$
 - at V_{CC} = 3 V
 - High-speed operation: t_{pd} = 1.9 ns (typ.) at V_{CC} = 3.3 V,15pF
- Operating voltage range: V_{CC} = 0.9~3.6 V
- 3.6-V tolerant input



Weight: 0.003 g (typ.)

Marking





Pin Assignment (top view)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	VIN	-0.5~4.6	V
DC output voltage	V _{OUT}	-0.5~ V _{CC} + 0.5	V
Input diode current	IIK	-20	mA
Output diode current	I _{OK}	±20 (Note 1)	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

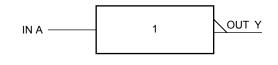
Note 1: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

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Truth Table

А	Y
L	Н
Н	L





Operating Ranges

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	0.9~3.6	V
Input voltage	V _{IN}	0~3.6	V
Output voltage	V _{OUT}	0~V _{CC}	V
Output Current	IOH/IOL	±8.0 (Note 2)	
		±4.0 (Note 3)	
		±3.0 (Note 4)	mA
		±1.7 (Note 5)	IIIA
		±0.3 (Note 6)	
		±0.02 (Note 7)	
Operating temperature	T _{opr}	-40~85	°C

Note 2: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 3: V_{CC} = 2.3~2.7 V

Note 4: V_{CC} = 1.65~1.95 V

Note 5: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 6: V_{CC} = 1.1~1.3 V

Note 7: $V_{CC} = 0.9 V$

DC Electrical Characteristics

Characteristics Symbol		Teet	Test Oser litier			Га = 25°С	C	Ta = -40~85°C		l Init
		Test Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High-level VIH input voltage				0.9	V _{CC}	_		V _{CC}	—	v
				1.1~1.3	$V_{CC} \times 0.8$		_	$V_{CC} \times 0.8$		
				1.4~1.6	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	
	VIH		—	1.65~ 1.95	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	
				2.3~2.7	V _{CC} × 0.8	_	_	V _{CC} × 0.8	_	
				3.0~3.6	V _{CC} × 0.8		_	V _{CC} × 0.8	_	
				0.9	_		GND	_	GND	
				1.1~1.3	_	_	V _{CC} × 0.2	_	$\begin{array}{c} V_{CC} \\ \times \ 0.2 \end{array}$	v
Low-level				1.4~1.6	_	_	$V_{CC} \times 0.2$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.2 \end{array}$	
input voltage	VIL			1.65~ 1.95	_	_	$V_{CC} \times 0.2$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.2 \end{array}$	
			2.3~2.7	—	_	V _{CC} × 0.2	—	$\begin{array}{c} V_{CC} \\ \times \ 0.2 \end{array}$		
				3.0~3.6	—	_	V _{CC} × 0.2	—	$\begin{array}{c} V_{CC} \\ \times \ 0.2 \end{array}$	
		$V_{IN} = V_{IL}$	I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	—	
			I _{OH} = -0.3 mA	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	—	V
High-level	Vон		I _{OH} = -1.7 mA	1.4~1.6	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		_	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$	_	
output voltage		V _{IN} =GND	I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45		—	V _{CC} -0.45	_	
			I _{OH} = -4.0 mA	2.3~2.7	2.0	_		2.0	—	
			I _{OH} = -8.0 mA	3.0~3.6	2.48			2.48	—	
		$V_{IN} = V_{IH}$	I _{OL} = 0.02 mA	0.9	—	—	0.1	—	0.1	
Low-level V output voltage			I _{OL} = 0.3 mA	1.1~1.3	_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	
	V _{OL}	1	I _{OL} = 1.7 mA	1.4~1.6	_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	V
		V _{IN} = V _{CC}	I _{OL} = 3.0 mA	1.65~ 1.95		_	0.45	—	0.45	
			I _{OL} = 4.0 mA	2.3~2.7	—		0.4	—	0.4	
			I _{OL} = 8.0 mA	3.0~3.6	—	_	0.4	—	0.4	
Input leakage current	I _{IN}	V _{IN} = 0~3.6V		0~3.6	_	_	±0.1	_	±1.0	μA
Quiescent supply current	ICC	$V_{IN} = V_{CC}$	or GND	3.6	_	_	1.0	_	10.0	μA

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		15.0		_		
			1.1~1.3	_	6.0	18.4	1.0	34.2	
			1.4~1.6	_	3.2	8.5	1.0	10.0	ns
			1.65~ 1.95	_	2.6	6.2	1.0	6.7	
			2.3~2.7	_	2.0	3.9	1.0	4.4	
Propagation delay time			3.0~3.6		1.7	3.1	1.0	3.7	
		$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	18.8	_	_	_	
	tрLH tpHL		1.1~1.3	_	7.0	21.5	1.0	37.2	
			1.4~1.6		3.5	9.3	1.0	11.2	
			1.65~ 1.95		3.0	6.9	1.0	7.1	
			2.3~2.7		2.3	4.4	1.0	5.0	
			3.0~3.6	_	1.9	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	33.0	_	_	_	
			1.1~1.3	_	12.0	29.6	1.0	56.0	
			1.4~1.6		6.0	13.1	1.0	15.9	
			1.65~ 1.95	_	4.5	9.2	1.0	9.6	
			2.3~2.7		3.2	5.7	1.0	6.1	
			3.0~3.6		2.5	4.4	1.0	4.8	
Input capacitance	C _{IN}	—	3.6		3	_	_	_	pF
Power dissipation capacitance	C _{PD}	(Note8)	0.9~3.6		8		—	_	pF

Note 8: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

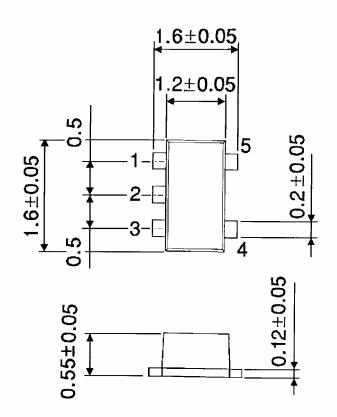
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SON5-P-0.50

Unit : mm



Weight: 0.003 g (typ.)

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20070701-EN GENERAL

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